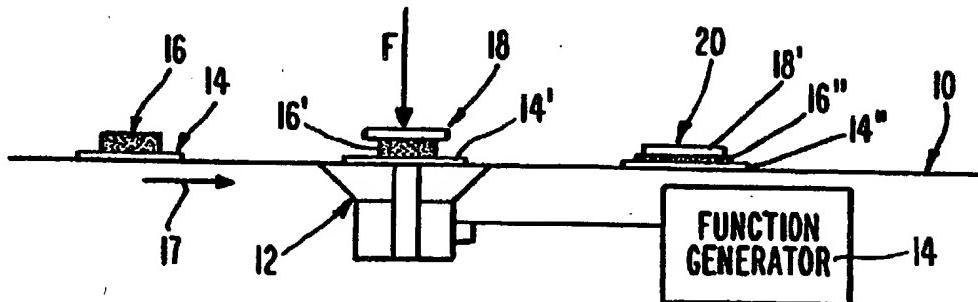




## INTERNATIONAL APPLICATION PUBLISHED UNDER THE PATENT COOPERATION TREATY (PCT)

(51) International Patent Classification 6 :	A1	(11) International Publication Number: WO 97/06953 (43) International Publication Date: 27 February 1997 (27.02.97)
B32B 31/00		
(21) International Application Number: PCT/US96/13226		(81) Designated States: AL, AM, AT, AU, AZ, BB, BG, BR, BY, CA, CH, CN, CZ, DE, DK, ER, ES, FI, GB, GE, HU, IL, IS, JP, KE, KG, KP, KR, KZ, LK, LR, LS, LT, LU, LV, MD, MG, MK, MN, MW, MX, NO, NZ, PL, PT, RO, RU, SD, SE, SG, SI, SK, TJ, TM, TR, TT, UA, UG, UZ, VN, ARIPO patent (KE, LS, MW, SD, SZ, UG), Eurasian patent (AM, AZ, BY, KG, KZ, MD, RU, TJ, TM), European patent (AT, BE, CH, DE, DK, ES, FI, FR, GB, GR, IE, IT, LU, MC, NL, PT, SE), OAPI patent (BF, BJ, CF, CG, CI, CM, GA, GN, ML, MR, NE, SN, TD, TG).
(22) International Filing Date: 16 August 1996 (16.08.96)		
(30) Priority Data:		
08/515,863 16 August 1995 (16.08.95) US		
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(54) Title: METHOD AND APPARATUS FOR BONDING MICROELECTRONIC CHIPS



## (57) Abstract

Disclosed is a die bonding system comprising a conveyor (10), a speaker (12) and a function generator (14). The conveyor (10) carries a leadframe (14) bearing a prescribed quantity of die bonding epoxy (16). At a station situated above the speaker (12), a chip (18) is pressed down with a force F onto the epoxy and leadframe. While this force is being applied, the function generator (14) excites the speaker (12) to generate an acoustic signal sufficient to effect the vibration of the epoxy relative to the leadframe at a frequency of about 250 Hz and an amplitude of approximately 10 to 50  $\mu\text{m}$ , preferably 20  $\mu\text{m}$ . Such a vibration causes the epoxy to flow freely to a thin, uniform thickness, and thus permits the chip to be quickly bonded to the leadframe with a small force.

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**METHOD AND APPARATUS FOR BONDING MICROELECTRONIC CHIPS****FIELD OF THE INVENTION**

The present invention relates generally to the  
5 field of bonding processes, and more particularly to die  
bonding of microelectronic chips.

**BACKGROUND OF THE INVENTION**

In microelectronic packages, two important  
functions are served by the die bond adhering the chip to  
10 the metal leadframe. First, the bond holds the chip  
securely in place so that electrical connections can be made  
in a subsequent operation. Second, the bond provides a path  
for conducting the heat generated by the chip to the  
leadframe, whence it is dissipated to the surroundings. The  
15 bond must be thin, uniform, and complete to avoid the  
development of hot spots on the chips, which may lead to  
thermal failure of the entire device. A silver-filled epoxy  
compound is commonly used as the bonding material, primarily  
because of its good thermal conductivity.

20 The die bonding process typically involves placing  
several drops of epoxy on the leadframe and then pressing  
the chip onto the leadframe with a constant force until a  
thin and uniform bond is achieved. This process takes a few  
tenths of a second with a 5 mm x 5 mm chip, and the bond  
25 thickness is typically 25  $\mu\text{m}$ . However, with increasing  
levels of circuit integration, the chips are becoming larger  
(e.g., up to 15 mm x 15 mm) and the time necessary to  
achieve the desired bond thickness is increasing

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- significantly. With very large chips, the desired bond thickness may, in fact, never be achieved. There are several reasons for this difficulty. Although improvements in die bonding machinery have decreased the time necessary
- 5 to pick and place the chips and to dispense the epoxy in carefully controlled amounts, the extrusion or squeezing of the epoxy is still problematic. In view of the thinness of the chips, the force applied for epoxy extrusion cannot be increased beyond a certain limiting value in order to avoid
- 10 chip material damage. Although newer chips have a larger surface area, they are not necessarily thicker and consequently can be more fragile. With a given magnitude of force and a chip size L, the pressure which drives the flow varies as  $1/L^2$ . Further, as the chip size increases, the
- 15 volume of epoxy to extrude from beneath the chip varies as  $L^2$ , but the area through which the epoxy extrudes (the outer edge of the die) varies only as L. Therefore, higher flow velocities and shear rates are necessary to complete the die bonding process.
- 20 One method of increasing the speed of the bonding process is to scrub the chip tangentially to the leadframe surface while applying a constant pressure. The scrubbing step involves moving the chip in a plane parallel to the leadframe surface, and often causes the epoxy to flow more
- 25 easily. A major problem with this process is that the chip must be gripped from the sides with a collet so that a tangential force may be imparted during scrubbing. Chips that are very thin and fragile are often damaged during this process.
- 30 U.S. Patent No. 4,145,390, March 20, 1979, titled "Process for Mounting Components on a Base by Means of a Thixotropic Material," discloses a bonding process whereby a thixotropic bonding material is vibrated, at an unspecified frequency in the range 1 Hz to 10 kHz and at a suggested
- 35 amplitude of 0.5 mm (500  $\mu\text{m}$ ), to increase the liquification of the thixotropic material. It is believed that this process is similar to, and suffers the same disadvantages

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of, the scrubbing process described above, in that the chip must be gripped from the sides so that the tangential vibrational force may be applied. Further, it is believed that the suggested vibrational amplitude of 500  $\mu\text{m}$  is too 5 large for many applications and will result in an unacceptable large number of damaged chips.

#### SUMMARY OF THE INVENTION

Accordingly, an object of the present invention is to provide an improved system for die bonding 10 microelectronic chips at a high speed without increasing the risk of damaging the chips.

According to the present invention, a method or system for bonding an integrated circuit chip to a lead frame comprises the steps of, or means for, applying an 15 adhesive to a surface of the lead frame, pressing the chip onto the surface on which the adhesive is applied, and inducing vibrations of a predetermined frequency and amplitude in at least the leadframe. The vibrations are induced with an acoustic source so that the adhesive 20 rheology is temporarily changed *in situ*. This permits the adhesive to flow to a predetermined thickness as the chip is pressed to a predetermined distance from the leadframe.

According to the invention, the epoxy rheology is changed temporarily *in situ* so that the epoxy flows more 25 easily. This step may be performed by placing a device comprising a small speaker driven by a function generator beneath the leadframes as the chips are being pressed down onto the leadframes. If the leadframes are vibrated with a small amplitude motion caused by the acoustic pressure from 30 the speaker, e.g., at a frequency of approximately 250 Hz and an amplitude of approximately 10-50  $\mu\text{m}$ , and preferably about 20  $\mu\text{m}$ , the epoxy will flow a great deal more freely. Calculations and experiments show that the flow time is greatly reduced for most chip sizes and forces. With the 35 prior art, the largest chips must be die bonded by hand because a simple constant force will not extrude the epoxy

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down to a thin enough film. Using the present invention, even the larger chips can be bonded automatically.

The risk of damaging the chip is small with the small amplitude, mid-frequency vibration employed by the 5 invention. Moreover, the vibration is preferably applied to the leadframe side of the chip/leadframe assembly, and most of it is absorbed in the epoxy, so the chip is not overly stressed. Further, with the low frequency, the required energy is relatively low.

- 10 Other features of the invention are described below.

#### BRIEF DESCRIPTION OF THE DRAWINGS

The figure depicts a presently preferred embodiment of a die bonding system in accordance with the 15 present invention.

#### DETAILED DESCRIPTION OF PREFERRED EMBODIMENTS

As shown in the drawing, a presently preferred embodiment of the invention comprises a conveyor 10, a speaker 12 and a function generator 14 arranged as shown. 20 The conveyor 10 carries a leadframe 14 bearing a prescribed quantity of die bonding epoxy 16 from left to right, as indicated by the arrow 17. At a station situated above the speaker 12, a chip 18 is pressed down with a force F onto the epoxy and leadframe, which are now labelled with 25 reference numerals 14' and 16'. The amount of force F is about 2 N. While this force is being applied, the function generator 14 excites the speaker 12 to generate an acoustic signal sufficient to effect the vibration of the epoxy 16' relative to the leadframe 14' at a frequency of about 250 Hz 30 and an amplitude of approximately 20  $\mu\text{m}$ . The present inventor has discovered that such a vibration will cause the epoxy to flow freely to a thin, uniform thickness, and thus will permit the chip 18 to be quickly bonded to the leadframe with a small force. The completed assembly 20 is

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then carried away from the bonding station so that the process can be repeated with other parts.

By increasing the efficiency of the die bonding process, by reducing the damaged parts and the time needed 5 to perform the process, the present invention could more than double the throughput of a die bonder making large chip packages. Such machines cost on the order of \$300,000. Therefore, the invention offers a potential savings of \$300,000 per machine installed.

10 As mentioned, the present invention provides a way of temporarily changing the epoxy rheology *in situ* so that the epoxy flows more easily, without gripping the chip. To the inventor's knowledge, no such method of flow enhancement has been employed previously in the microelectronics 15 industry. The phenomenon underlying the invention is not limited to die bonding epoxy, but rather seems to affect fluids generally known as yield stress fluids. The effect has been demonstrated on die bonding epoxy, toothpaste, and mustard (for example, at about 275 Hz, the yield stress of 20 mustard is so reduced that it becomes nearly Newtonian), but appears to be absent in Newtonian fluids such as oil and honey.

Variations and modifications of the particulars described above within the true spirit of the invention will 25 be apparent to those skilled in the art in view of the present disclosure, and therefore, except as they may be expressly so limited, the scope of protection of the following claims is not limited to the particulars described above.

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I claim:

1. A method of bonding an integrated circuit chip to a lead frame, comprising the steps of:
  - applying an adhesive to a surface of said lead frame;
  - pressing the chip onto said surface on which the adhesive is applied; and
  - inducing, with an acoustic source, vibrations of a predetermined frequency and amplitude in at least said leadframe, whereby the adhesive rheology is temporarily changed *in situ* so that the adhesive flows to a predetermined thickness to permit the chip to be pressed to a predetermined distance from said leadframe.
2. The method recited in claim 1 wherein said adhesive comprises an epoxy compound.
3. The method recited in claim 1 wherein the pressing step comprises pressing the chip onto said surface with a constant force.
4. The method recited in claim 1 wherein said step of inducing vibrations in at least said leadframe comprises subjecting at least said leadframe to acoustic pressure waves characterized by a frequency of approximately 250 Hz and an amplitude of approximately 10-50  $\mu\text{m}$ .
5. The method recited in claim 4 wherein the acoustic pressure waves are generated by a speaker.
6. The method recited in claim 5 wherein said adhesive comprises an epoxy compound, and the pressing step comprises pressing the chip onto said surface with a constant force.

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7. A die bonding system for bonding an integrated circuit chip to a surface of a leadframe, wherein an adhesive is carried on said surface, comprising:

means for pressing the chip onto said surface on  
5 which the adhesive is applied; and

means for inducing, with an acoustic source,  
vibrations of a predetermined frequency and amplitude in at  
least said leadframe, whereby the adhesive rheology is  
temporarily changed *in situ* so that the adhesive flows to a  
10 predetermined thickness to permit the chip to be pressed to  
a predetermined distance from said leadframe.

8. The system recited in claim 7 wherein said adhesive comprises an epoxy compound.

9. The system recited in claim 7 wherein the  
15 means for pressing comprises means for pressing the chip  
onto said surface with a constant force.

10. The system recited in claim 7 wherein said  
means for inducing vibrations in at least said leadframe  
subjects at least said leadframe to acoustic pressure waves  
20 characterized by a frequency of approximately 250 Hz and an  
amplitude of approximately 10-50  $\mu\text{m}$ .

11. The system recited in claim 10 wherein said  
means for inducing vibrations comprises a speaker.

12. The system recited in claim 11 wherein said  
25 means for inducing vibrations further comprises a function  
generator operatively coupled to said speaker.

13. The system recited in claim 12 wherein said  
adhesive comprises an epoxy compound, and said means for  
pressing comprises means for pressing the chip onto said  
30 surface with a constant force.

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14. A process for die bonding a microelectronic chip to a leadframe with an adhesive characterized as a yield stress fluid, comprising the steps of temporarily changing *in situ* the rheology of said adhesive without gripping said chip, and pressing said chip so that said adhesive flows to a predetermined thickness and said chip is positioned a predetermined distance from said leadframe.

15. The process recited in claim 14 comprising inducing acoustic vibrations of a predetermined frequency 10 and amplitude in at least said leadframe.

16. The process recited in claim 15 wherein said predetermined frequency is approximately 250 Hz.

17. The process recited in claim 15 wherein said predetermined amplitude is approximately 10-50  $\mu\text{m}$ .

15 18. The process recited in claim 16 wherein said predetermined amplitude is approximately 10-50  $\mu\text{m}$ .

19. The process recited in claim 17 wherein said predetermined amplitude is approximately 20  $\mu\text{m}$ .

20. The process recited in claim 18 wherein said 20 predetermined amplitude is approximately 20  $\mu\text{m}$ .

21. The method recited in claim 4 wherein said predetermined amplitude is approximately 20  $\mu\text{m}$ .

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22. The system recited in claim 10 wherein said predetermined amplitude is approximately 20  $\mu\text{m}$ .

## AMENDED CLAIMS

[received by the International Bureau on 12 December 1996 (12.12.96);  
original claims 1, 4, 5, 7, 10, 11, 14 and 21 amended;  
remaining claims unchanged (5 pages)]

1. A method of bonding an integrated circuit chip to a lead frame, comprising the steps of:
  - applying an adhesive to a surface of said lead frame;
  - pressing the chip onto said surface on which the adhesive is applied; and
  - inducing, with an acoustic source, vibrations of a predetermined frequency and amplitude in at least said leadframe, said amplitude being approximately 10-50  $\mu\text{m}$ , whereby the adhesive rheology is temporarily changed *in situ* so that the adhesive flows to a predetermined thickness to permit the chip to be pressed to a predetermined distance from said leadframe.
- 15 2. The method recited in claim 1 wherein said adhesive comprises an epoxy compound.
- 20 3. The method recited in claim 1 wherein the pressing step comprises pressing the chip onto said surface with a constant force.
- 25 4. The method recited in claim 1 wherein said step of inducing vibrations in at least said leadframe further comprises subjecting at least said leadframe to acoustic pressure waves characterized by a frequency of approximately 250 Hz and an amplitude of approximately 20  $\mu\text{m}$ .
- 30 5. The method recited in claim 1 wherein the acoustic pressure waves are generated by a speaker situated such that said acoustic waves induce a vibrational force in said adhesive and chip, said force being substantially perpendicular to the chip surface in contact with said adhesive.
- 35

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6. The method recited in claim 5 wherein said adhesive comprises an epoxy compound, and the pressing step comprises pressing the chip onto said surface with a constant force.

5

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7. A die bonding system for bonding an integrated circuit chip to a surface of a leadframe, wherein an adhesive is carried on said surface, comprising:

means for pressing the chip onto said surface on  
5 which the adhesive is applied; and

means for inducing, with an acoustic source, vibrations of a predetermined frequency and amplitude in at least said leadframe, said amplitude being approximately 10-50  $\mu\text{m}$ , whereby the adhesive rheology is temporarily changed  
10 in situ so that the adhesive flows to a predetermined thickness to permit the chip to be pressed to a predetermined distance from said leadframe.

8. The system recited in claim 7 wherein said  
15 adhesive comprises an epoxy compound.

9. The system recited in claim 7 wherein the means for pressing comprises means for pressing the chip onto said surface with a constant force.

20  
10. The system recited in claim 7 wherein said means for inducing vibrations in at least said leadframe subjects at least said leadframe to acoustic pressure waves characterized by a frequency of approximately 250 Hz and an  
25 amplitude of approximately 20  $\mu\text{m}$ .

11. The system recited in claim 7 wherein said means for inducing vibrations comprises a speaker situated such that said acoustic waves induce a vibrational force in  
30 said adhesive and chip that is substantially perpendicular to the surface of said chip in contact with said adhesive.

12. The system recited in claim 11 wherein said means for inducing vibrations further comprises a function  
35 generator operatively coupled to said speaker.

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13. The system recited in claim 12 wherein said adhesive comprises an epoxy compound, and said means for pressing comprises means for pressing the chip onto said surface with a constant force.

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14. A process for die bonding a microelectronic chip to a leadframe with an adhesive characterized as a yield stress fluid, comprising the steps of temporarily changing *in situ* the rheology of said adhesive without  
5 gripping said chip by inducing a vibrational force in a direction which is substantially perpendicular to a surface of said chip which is in contact with said adhesive, and pressing said chip so that said adhesive flows to a predetermined thickness and said chip is positioned a  
10 predetermined distance from said leadframe.

15. The process recited in claim 14 comprising inducing acoustic vibrations of a predetermined frequency and amplitude in at least said leadframe.

15

16. The process recited in claim 15 wherein said predetermined frequency is approximately 250 Hz.

17. The process recited in claim 15 wherein said  
20 predetermined amplitude is approximately 10-50  $\mu\text{m}$ .

18. The process recited in claim 16 wherein said predetermined amplitude is approximately 10-50  $\mu\text{m}$ .

25

19. The process recited in claim 17 wherein said predetermined amplitude is approximately 20  $\mu\text{m}$ .

20. The process recited in claim 18 wherein said predetermined amplitude is approximately 20  $\mu\text{m}$ .

30

21. The process recited in claim 5, wherein said predetermined amplitude is approximately 20  $\mu\text{m}$ .

22. The system recited in claim 10 wherein said  
35 predetermined amplitude is approximately 20  $\mu\text{m}$ .

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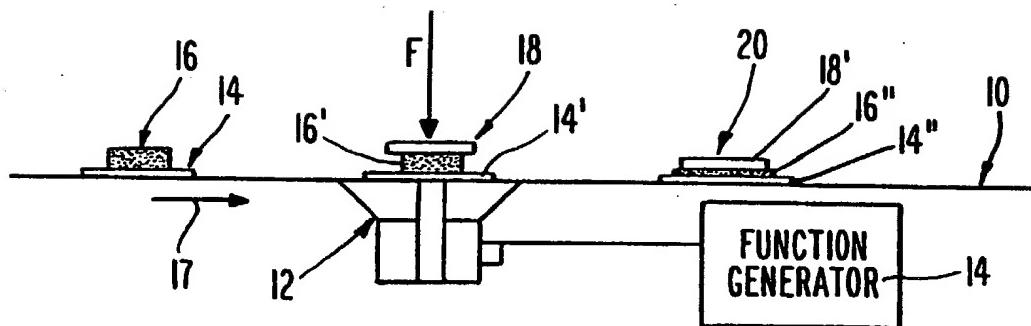


Fig. 1

SUBSTITUTE SHEET (RULE 26)

## INTERNATIONAL SEARCH REPORT

International application No.

PCT/US96/13226

**A. CLASSIFICATION OF SUBJECT MATTER**

IPC(6) :B32B 31/00

US CL :156/73.6,580

According to International Patent Classification (IPC) or to both national classification and IPC

**B. FIELDS SEARCHED**

Minimum documentation searched (classification system followed by classification symbols)

U.S. : 156/73.1,73.5,73.6,580,580.1,580.2

Documentation searched other than minimum documentation to the extent that such documents are included in the fields searched

Electronic data base consulted during the international search (name of data base and, where practicable, search terms used)

**C. DOCUMENTS CONSIDERED TO BE RELEVANT**

Category*	Citation of document, with indication, where appropriate, of the relevant passages	Relevant to claim No.
Y	US, A, 4,145,390 (ZSCHIMMER) 20 March 1979, col. 1, line 20 through col. 2, line 40.	1-22
Y	US, A, 4,831,724 (ELLIOTT) 23 May 1989, col. 4, line 12 through col. 5, line 52.	1-22

Further documents are listed in the continuation of Box C.

See patent family annex.

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Date of the actual completion of the international search  
24 SEPTEMBER 1996

Date of mailing of the international search report

29 OCT 1996

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